

Experimental Design of Stencil-Printed High-Performance Organic Electrochemical Transistor

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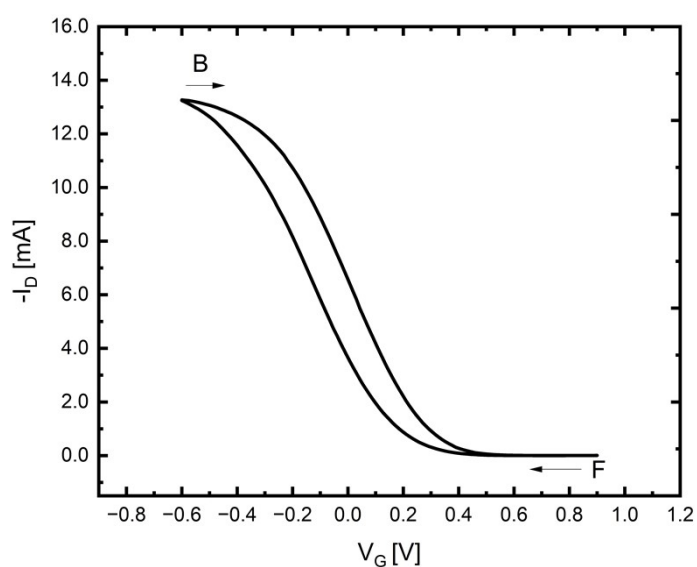


Figure S11 Transfer Curve of the optimized device (Forward/Backward)

Table. S1 The Experimental Plan reporting average and standard deviation of each response

<i>L (mm)</i>	<i>T (C)</i>	<i>t (min)</i>	<i>on/off ratio</i>	<i>g_m (mS)</i>	<i>V_T (V)</i>
1.5	90	10	10100 ± 2000	29.0 ± 6.8	0.27 ± 0.07
2.5	90	10	8050 ± 450	29.1 ± 0.3	0.37 ± 0.01
1.5	90	120	6900 ± 700	30.0 ± 3.0	0.46 ± 0.01
2.5	90	120	5600 ± 200	26.9 ± 0.1	0.46 ± 0.01
2.0	115	65	7550 ± 660	31.0 ± 4.9	0.50 ± 0.07
1.5	140	10	2800 ± 300	29.8 ± 0.9	0.62 ± 0.01
2.5	140	10	4500 ± 1100	28.6 ± 5.9	0.56 ± 0.08
1.5	140	120	1270 ± 170	24.8 ± 2.9	0.65 ± 0.03
2.5	140	120	1970 ± 820	26.9 ± 3.8	0.53 ± 0.03
2.0	90	10	6800 ± 1900	22.5 ± 4.3	0.26 ± 0.03

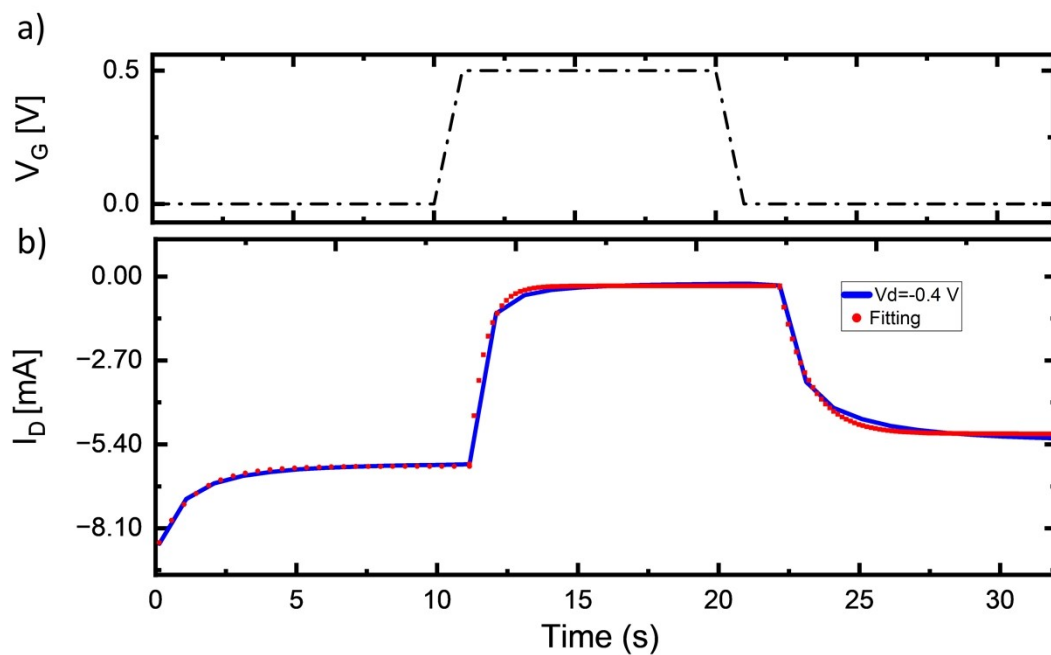


Figure S12 measured time response of an OECT in response to a square step of the gate voltage while V_D maintained constant (-0.4 V). a) a square V_G pulse of 0.5 V b) monotonic relaxation of I_D toward steady state fitted using Bernard's model and estimated time constant is 0.52s.

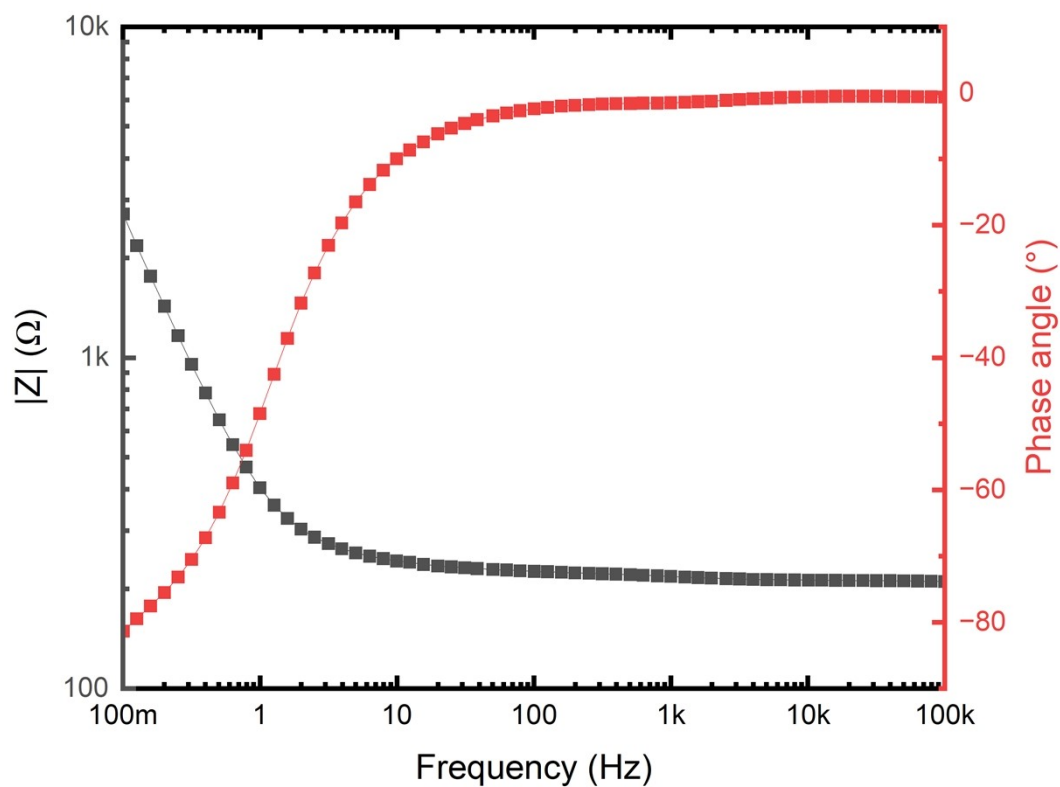


Figure S13 Bode plots of Electrochemical impedance spectroscopy (EIS) measurement (Counter electrode: platinum wire, working electrode: PEDOT:PSS channel, Reference electrode: Ag/AgCl wire). An equivalent circuit model (Randles) was fitted. The extracted value of raw capacitance is 0.5 mF and volumetric capacitance C^* is 4 F/cm³.

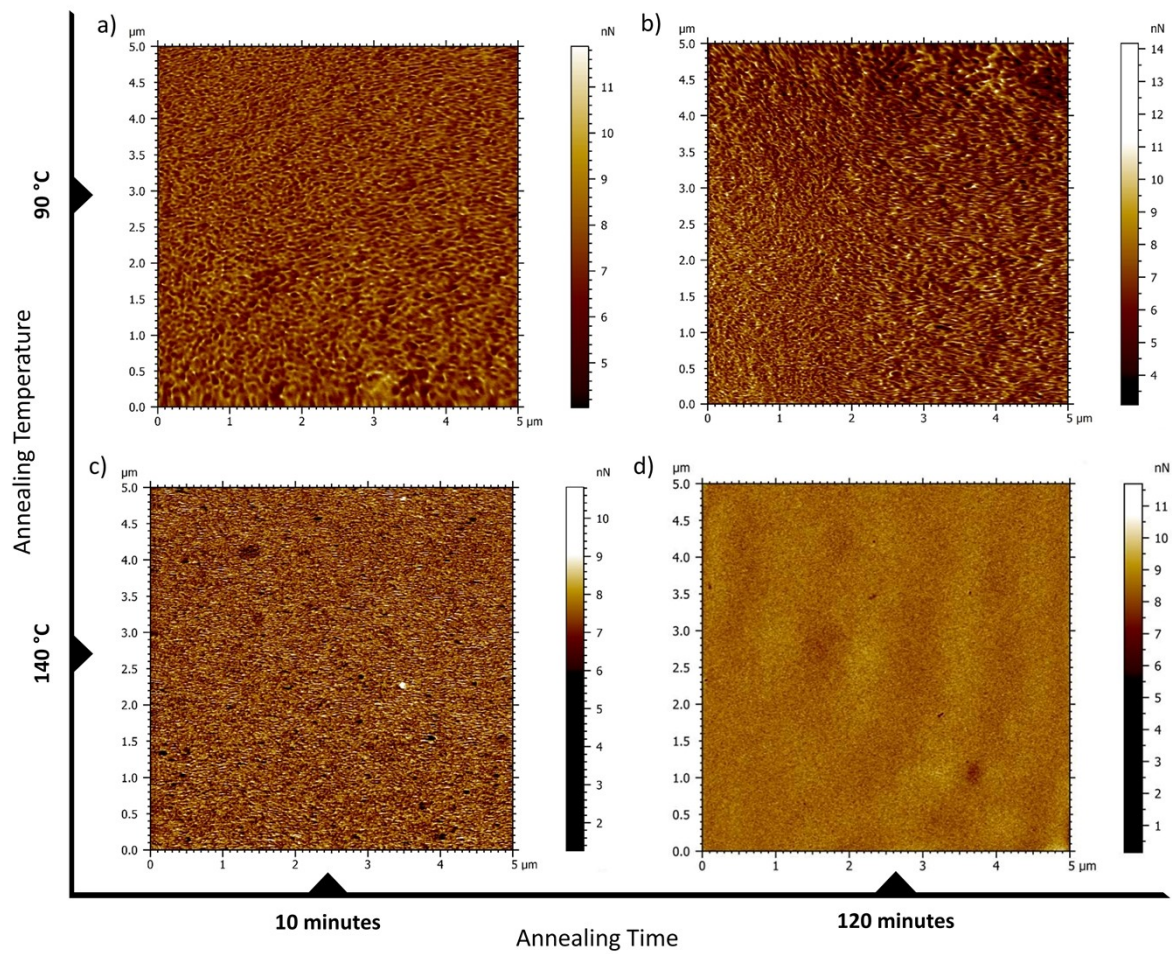


Figure SI4 Representative $5 \mu\text{m} \times 5 \mu\text{m}$ adhesion maps of the channel region of 4 devices with $L = 1.5 \text{ mm}$, and in a) $T = 90 \text{ }^\circ\text{C}$ and $t = 10 \text{ minutes}$, b) $T = 90 \text{ }^\circ\text{C}$ and $t = 120 \text{ minutes}$, c) $T = 140 \text{ }^\circ\text{C}$ and $t = 10 \text{ minutes}$, d) $T = 140 \text{ }^\circ\text{C}$ and $t = 120 \text{ minutes}$.

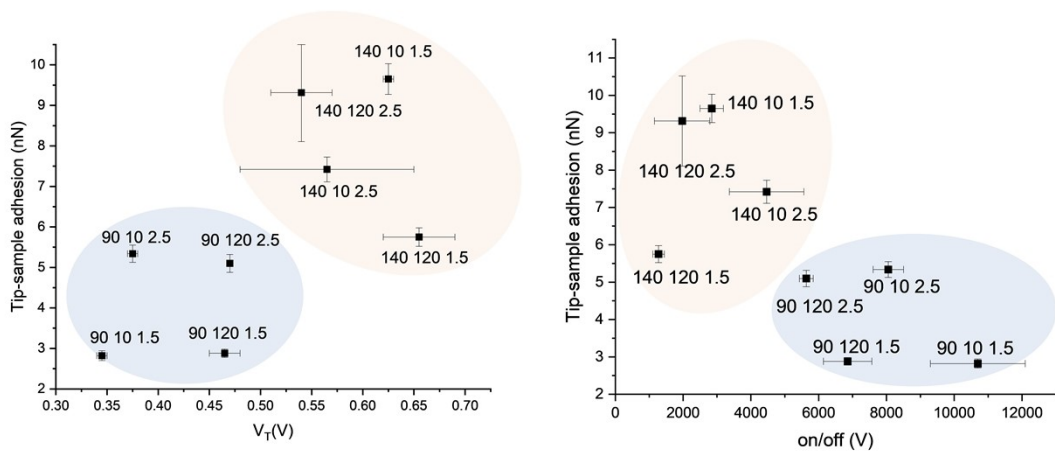


Figure SI5 The tip-surface adhesion of the OECTs measured with AFM plotted versus the on/off ratio (left) and the V_T (right). Blue is $90 \text{ }^\circ\text{C}$, pink is $140 \text{ }^\circ\text{C}$.